

LR6212

1.28 Watt Audio Power Amplifier

Features

- □ Improved PSRR at 217 Hz & 1 KHz 62 dB
- **Ο** Power output at 5.0V, 1% THD+N, 8Ω
- **D** Power output at 3.0V, 1% THD+N, 8 Ω 440 mW (typ.)
- Ultra low shutdown current
- \Box 2.2V 5.5V operation
- □ Improved circuitry eliminates pop-click noise during turn-on and turn-off transitions

1.28 W (typ.)

0.1 uA (typ.)

- □ No output coupling capacitors, snubber networks or bootstrap capacitors required
- □ Unity-gain stable
- External gain configuration capability
- □ Available in space-saving packages: MSOP8, 9-BUMP WLCSP

General Description

The LR6212 is a Class-AB audio power amplifier designed for mobile phones and other portable communication devices. It is capable of delivering 1.28 watts of continuous average power to an 8Ω BTL load with less than 1% distortion (THD+N) from a 5V_{DC} power supply.

The LR6212 was designed specifically to provide high quality output power with a minimal amount of external components. It does not require output coupling capacitors or bootstrap capacitors. And with ultra low shutdown current, the LR6212 is ideally suited for mobile phone and other low voltage applications where minimal power consumption is a primary requirement.

With special pop-click eliminating circuit, the LR6212 provides perfect pop-click characteristic during turn-on and turn-off transitions.

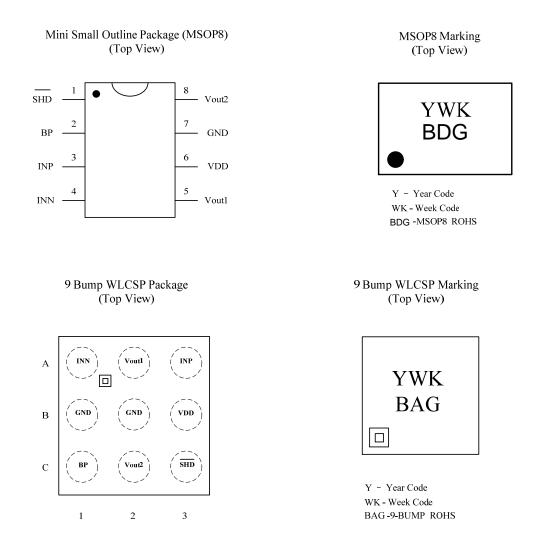
The LR6212 is unity-gain stable and can be configured by external gain-setting resistors.

Applications

- Wireless handsets
- □ Portable electronic devices
- D PDAs, Handheld computers



Pin Diagrams



Pin Description

No.	Pin Name	I/O	Description
1	SHD	Ι	Shout-down Logical Control, '0' is active.
2	BP	I/O	Analog ground for inner OPAs. It's about a half of VDD.
3	INP	Ι	Positive Input
4	INN	Ι	Negative Input
5	Vout1	0	Negative BTL Output
6	VDD	I/O	Power Supply $(2.2 - 5.5 \text{ V})$
7	GND	I/O	Ground
8	Vout2	0	Positive BTL Output



Typical Application Circuit

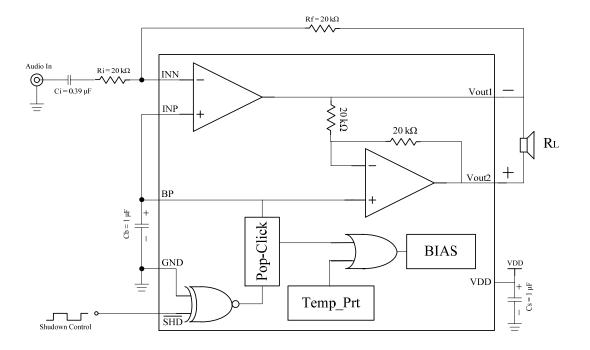
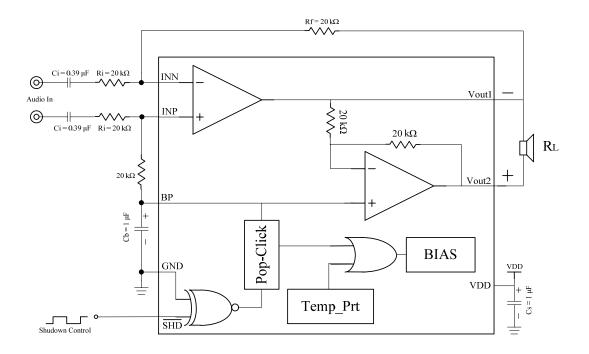
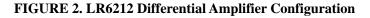


FIGURE 1. LR6212 Typical Application Circuit









External Components Description

Components	Functional Description
Ri	Inverting input resistance which sets the closed-loop gain in conjunction with
	Rf. This resistor also forms a high pass filter with Ci at $fc = 1/(2\pi Ri^*Ci)$.
Ci	Input coupling capacitor which blocks the DC voltage at the amplifiers input
	terminates. Also creates a high-pass filter with Ri at $fc = 1/(2\pi Ri^*Ci)$.
Rf	Feedback resistance which sets the closed-loop gain in conjunction with Ri.
Cs	Supply bypass capacitor which provides power supply filtering.
Cb	Bypass pin capacitor which provides half-supply filtering. Refer to the section.

Absolute Maximum Ratings

Supply Voltage	-0.3V to 6V
Input Voltage	-0.3V to VDD+0.3V
Power Dissipation	
See D	issipation Rating Table
ESD Susceptibility	(Human body model)
	4000V
Junction Temperature	-40° C to $+150^{\circ}$ C
Storage Temperature	-65℃ to +150℃
Thermal Resistance	
$\theta_{JC}(MSOP8)$	56°C/W
$\theta_{JA}(MSOP8)$	190°C/W
$\theta_{JA}(9\text{-BUMP})$	180°C/W

Operating Ratings

Temperature Range	$-40^{\circ}\mathrm{C} \leq T_{\mathrm{A}} \leq 85^{\circ}\mathrm{C}$
Supply Voltage	$2.2\mathrm{V}\!\leq\!\mathrm{V}_{\mathrm{DD}}\!\leq\!5.5\mathrm{V}$

NOTE: <u>Absolute Maximum Ratings indicate limits</u> beond which damage to the device may occur. Operating Rating indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Electrical Characteristics

The following specifications apply for the circuit shown in Figure 1, unless otherwise specified. Limits apply for $T_A = 25$ °C.

$\Box \quad V_{DD} = 5V$

Symbol	Parameter	Conditions	Spec			Units
Symbol	rarameter	Conditions	Min.	Тур.	Max.	Units
т	Quiescent Power Supply Current	$V_{IN} = 0V$, 8Ω Load		2.4	8	mA
I _{DD}		$V_{IN} = 0V$, No Load		2.1	7	mA
I _{SD}	Shutdown Current	V _{IN} =0V, V _{SHD} =GND, No Load		0.1	2	uA
V _{SDIH}	Shutdown Voltage Input High			1.58		V
V _{SDIL}	Shutdown Voltage Input Low			1.36		V
V _{os}	Output Offset Voltage		-50	6	50	mV



THD+N	Total Harmonic Distortion+Noise	Po=0.5Wrms, f=1KHz,		0.04		%
Po	Output Power	THD+N<=1%, f=1KHz,	0.9	1.28		W
0	o alpart of or	8Ω Load	0.9			
	PSRR Power Supply Rejection Ratio	Input terminated with 10Ω ,	55	60		dB
DCDD		V _{DDRIPPLE} =0.2V _{P-P} , f=217Hz	55			uВ
I SKK		Input terminated with 10Ω ,	55	64		dB
		V _{DDRIPPLE} =0.2V _{P-P} , f=1KHz	55	04		uВ
T_{WU}	Wake-up time			100		ms
R _{OUT}	Resistor Output to GND		5.8	7.3	9.7	kΩ

$\Box \quad V_{DD} = 3V$

Ch al	Demonster	Con litions	Spec			Units	
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units	
т		$V_{IN} = 0V$, 8Ω Load		1.9	7	mA	
I _{DD}	Quiescent Power Supply Current	$V_{IN} = 0V$, No Load		1.7	6	mA	
I _{SD}	Shutdown Current	V _{IN} =0V, V _{SHD} =GND, No Load		0.1	2	uA	
V _{SDIH}	Shutdown Voltage Input High			1.27		V	
V _{SDIL}	Shutdown Voltage Input Low			1.08		V	
V _{OS}	Output Offset Voltage		-50	6	50	mV	
THD+N	Total Harmonic Distortion+Noise	Po=0.25Wrms, f=1KHz,		0.06		%	
Po	Output Power	THD+N<=1%, f=1KHz, 8Ω Load		440		mW	
DCDD	Dower Supply Dejection Detic	Input terminated with 10Ω, V _{DDRIPPLE} =0.2V _{P-P} , f=217Hz	55	62		dB	
PSRR	Power Supply Rejection Ratio	Input terminated with 10Ω, V _{DDRIPPLE} =0.2V _{P-P} , f=1KHz	55	68		dB	
T_{WU}	Wake-up time			75		ms	
R _{OUT}	Resistor Output to GND		5.8	7.3	9.7	kΩ	

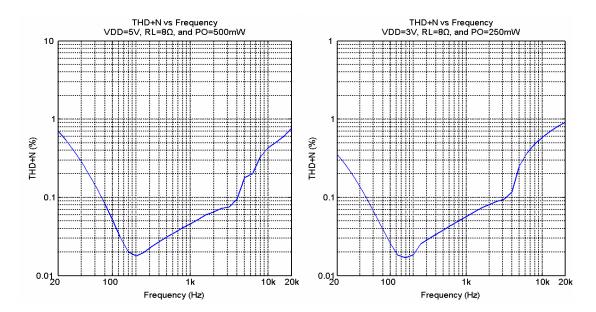
$\Box \quad V_{DD} = 2.6V$

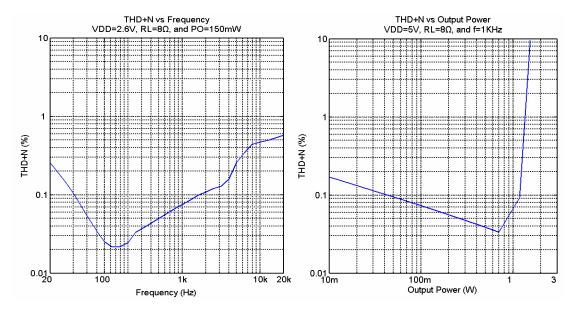
Symbol	Parameter	Conditions	Spec			Units
	Parameter	Conditions	Min.	Тур.	Max.	Units
т	Quiagaant Bawar Supply Current	$V_{IN} = 0V$, 8Ω Load		1.7		mA
I _{DD}	Quiescent Power Supply Current	$V_{IN} = 0V$, No Load		1.47		mA
I _{SD}	Shutdown Current	V _{IN} =0V, V _{SHD} =GND, No Load		0.1		uA
V _{SDIH}	Shutdown Voltage Input High	utdown Voltage Input High		1.20		V
V _{SDIL}	Shutdown Voltage Input Low			1.01		V
V _{OS}	Output Offset Voltage		-50	4	50	mV
THD+N	Total Harmonic Distortion+Noise	Po=0.15Wrms, f=1KHz,		0.08		%



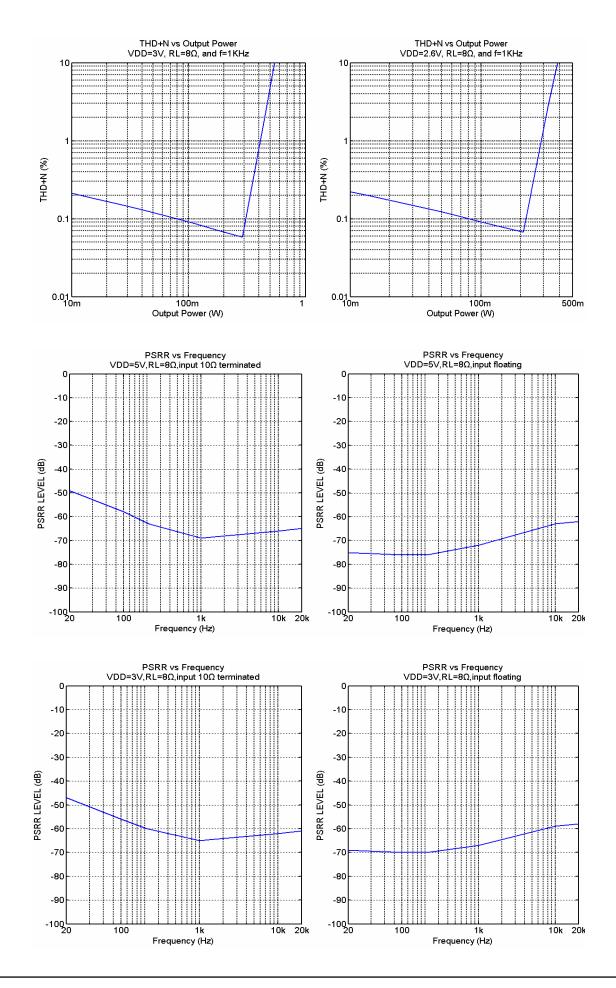
Po	Output Power	THD+N<=1%, f=1KHz,		320		mW
10		8Ω Load				
	PSRR Power Supply Rejection Ratio	Input terminated with 10Ω ,	51	56		dB
DCDD		V _{DDRIPPLE} =0.2V _{P-P} , f=217Hz	51			цБ
FSKK		Input terminated with 10Ω ,		50		ID
		V _{DDRIPPLE} =0.2V _{P-P} , f=1KHz	51	59		dB
T_{WU}	Wake-up time			70		ms
R _{OUT}	Resistor Output to GND		5.8	7.3	9.7	kΩ

Typical Performance Characteristics

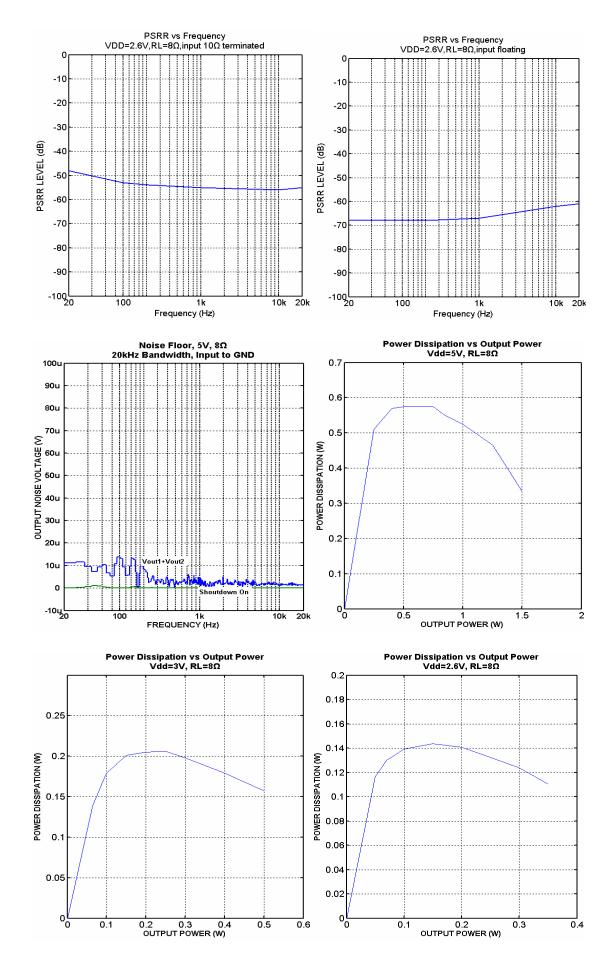




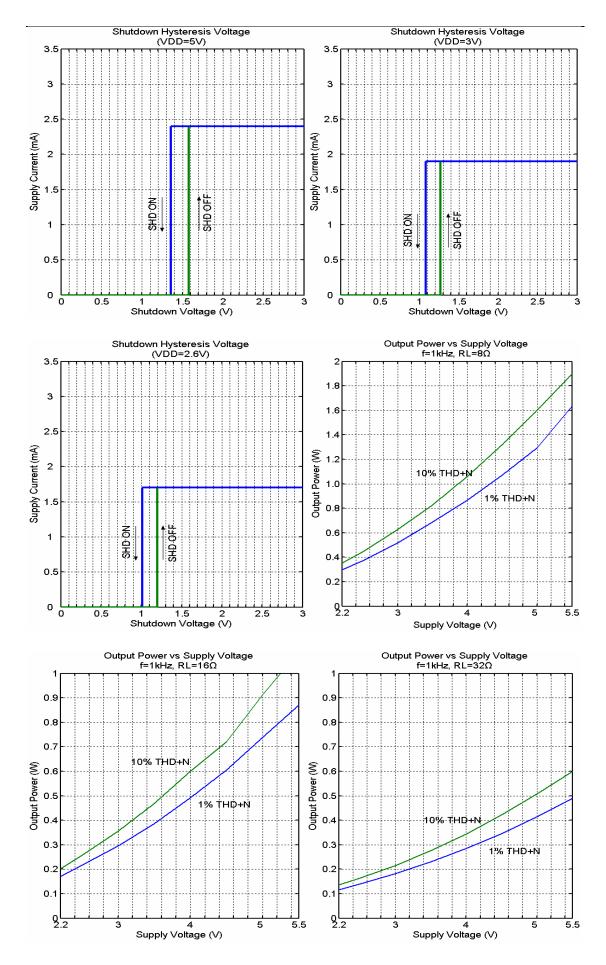












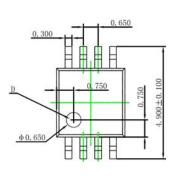


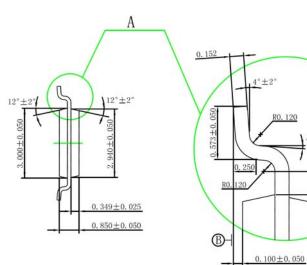
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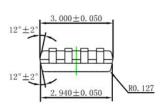
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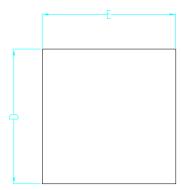
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Package Dimensions

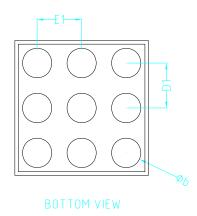


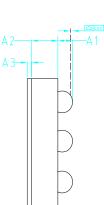






TOP VIEW





MSOP8

All dimension values are in millimeter.

9 Bump WLCSP Dimensions (mm)

REF	MIN	ТҮР	MAX
A1	0.215	0.235	0.255
A2	0.355	0.380	0.405
A3	0.020	0.035	0.050
D	1.485	1.500	1.515
D1		0.500	
Е	1.485	1.500	1.515
E1		0.500	
b	0.300	0.320	0.340
CCC		0.080	



单击下面可查看定价,库存,交付和生命周期等信息

>>LRC(乐山无线电)